# NSN 5961-01-235-6806

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#### **Inclosure Material:**

Metal

**Overall Length:** 

1.570 inches

# **Overall Height:**

0.350 inches

**Overall Width:** 

1.050 inches

# **Mounting Facility Quantity:**

2

#### Internal Configuration:

Junction contact

# Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

#### **Mounting Method:**

Unthreaded hole

# Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

120.0 collector to base voltage, dc and 100.0 collector to emitter voltage, dc and 6.0 emitter to base voltage, dc

#### **Current Rating Per Characteristic:**

50.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

250.0 watts small-signal input power, common-collector preset

#### **Transfer Ratio:**

10.0 static forward current transfer ratio, common-emitter

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Terminal Type And Quantity:**

2 pin and 1 case

#### Shelf Life:

N/a

# Unit Of Measure:

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#### **Demilitarization:**

No

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